NSN 5961-01-146-3016

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-146-3016 **Inclosure Material:** Glass **Overall Length:** Between 0.140 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.055 inches and 0.130 inches **End Application:** Monitor volt. 94271 **Mounting Method: Terminal Features Provided:** Hermetically sealed case and quality assurance level tx **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 480.0 nonrepetitive peak reverse voltage and 400.0 working peak reverse voltage **Current Rating Per Characteristic:** 400.00 milliamperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Item must comply with requirements of defense electronics supply center production standard no. L03243; for navy nuclear propulsion plant products only; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No